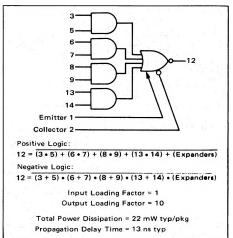
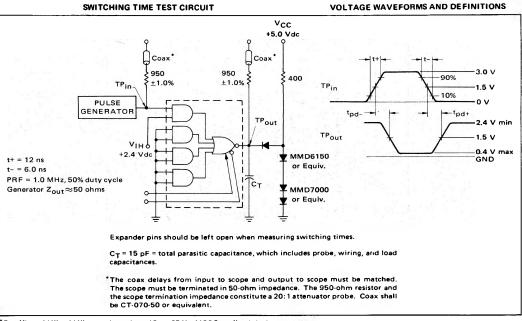


This device consists of four 2-input AND gates ORed together and inverted. Up to four MCB5460 expander gates may be ORed with the device at the expander points. Beam lead sealed junction technology is used to manufacture these devices. They are particularly useful in highly reliable systems using hybrid beam lead assembly techniques or standard flat package assembly techniques.





*F suffix = 1/4" x 1/4" ceramic package (Case 651). MCBC-prefixed devices are unencapsulated. Beam numbers are the same as the pin numbers for flat-packaged devices. See General Information section for package and chip details.

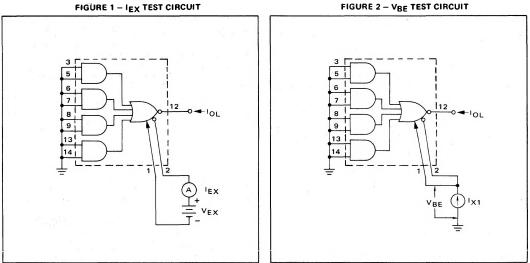
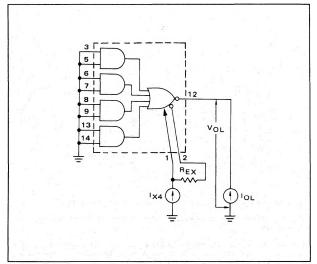


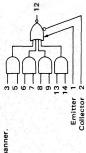
FIGURE 2 - VBE TEST CIRCUIT

FIGURE 3 - VOL TEST CIRCUIT



ELECTRICAL CHARACTERISTICS

Test procedures are shown for one input of the device. To complete testing, sequence through remaining inputs in a simi-lar manner.



		L L	e								TEST	TEST CURRENT / VOLTAGE VALUES (All Temperatures)	IT/VOLTA	AGE VA	TUES (F	VII Temp	erature	()					-	
	13 -	7	1					mA				Ohms					-	Volts						
1 Emitter	<u></u>		1		-3	lot	HOI	Ixi	1 _{x2}	I _{x3}	1×4	R _{EX} 3	Vex	VIL	VIH V	VIHH	VR1	V _{R2}	V.h. 1	V.ho	Vcc Vcci	Vcci	VCCH	
Collector	2		1			16	-0.4	0.41	0.41 0.27	-0.27	0.3	138	0.4	0.4	2.4	5.5	4.5	5.0	2.0	0.8	5.0	4.5	5.5	
		Pin		Test Limits BC5453/MCB545 	Test Limits MCBC5453/MCB5453F Kt to +175°C						rest cu	IRRENT / V	FET CURRENT / VOLTAGE APPLIED TO PINS LISTED BELOW:	APPLIE	D TO P	INS LIST	ED BELC	. MO						
Characteristic	Symbol	Test	×	Max	Unit	10	HO	Ixi	1 _{x2}	1 _{x3}	1 _{X4}	R _{EX} 3	V _{EX}	VIL	V _{IH}	VIHH	VRI	VR2	VAL	V _{th0}	Vcc	Vcc Vcci Vcch	VCCH	Gnd
Input Forward Current	IF	en	i.	-1.6	mAde		4		1		÷.		a constant	3	3	÷	ŝ	w.		4			*	11
Leakage Current	1 _{R1}	6	d)	40	µAdc.		a.	1	i.		1	1	() ()	· •	3	1	1			1			4	3,6,7,8,9, 11,13,14
	I _{R2}	8		1.0	mAde	ł.	÷.	1	1	1	1		1	й÷.,	1	3	2	1	201	4		ò.	4	3,6,7,8,9, 11,13,14
Expander Input Current	¹ EX	2 ①	1	-2.9	mAde	12	2	1-	50		5		1.2	1	1	1	1	1	1			*		3,5,6,7,8,9, 11,13,14
Base-Emitter Voltage	VBE	1 2	- •	1.0	Vdc	12		1,2	1				,	•	•	,	•		•	,		4	a.	3,5,6,7,8,9, 11,13,14
Output Output Voltage	VoL	12	0	0.4	Vdc	12		-	-				6	3				4	3,5			4	1	6,7,8,9, 11,13,14
		12 3		0.4	Vde	12	-	1		-	1	2	,	•	•	'			•			*	÷	3,5,6,7,8,9, 11,13,14
	V _{OH}	12	2.4	÷	Vdc		12	4	ыř.		a.	1	9	1			3,7, 9,14	e.	3	5,6,8,		4	а.	п
		12	2.4	9	Vdc		12	4	1	5	•				ŀ	•	'		•	•	•	4	•	3,5,6,7,8,9, 11,13,14
Short-Circuit Current	lsc	12	-20	-55	mAdc	4			•	·				1	•	•	•				•		4	3,5,6,7,8,9,11, 12,13,14
Power Requirements Power Supply Drain	HOd	4		9.5	mAdc	,	•	,	•	•	,	ı	ı.		,	,	•	3,5,6,7,8, 9,13,14	1	4		1	4	н
	Ipdl	4	4	8.0	mAdc		•	•	•	•	•		•	•	•	'			1	•	•		4	3,5,6,7,8,9, 11,13,14
Switching Parameters						Pulse In	Pulse Out														11			

** Tested only at 25°C.

6,7,8,9, 11,13,14

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pd. +pd

Turn-On Delay Turn-Off Delay

1 . 3,12 3,12

6,7,8,9, 11,13,14

• . 4 4

> ł. ,

> > See Figure 1.
> > See Figure 2.
> > See Figure 3.

MCBC5453, MCB5453F (continued)